

UNISONIC TECHNOLOGIES CO., LTD

US251 CMOS IC

CURRENT-LIMITED, POWER-DISTRIBUTION **SWITCHES**

DESCRIPTION

The UTC US251 is a power distribution switch. It is intended for applications such as USB where heavy capacitive loads and short-circuits are likely to be encountered. This family offers multiple devices with fixed current-limit thresholds for applications between 0.5A and 2A.

The $R_{DS(ON)}$ of the MOSFET switch is as low as $80m\Omega$. \overline{OC} is open-drain output report over-current or over-temperature event which has deglitch typical 9ms timeout period typically 9ms.

The UTC US251 incorporates protection circuits including current limiting circuit with foldback function, thermal shutdown circuit designed to prevent catastrophic switch failure due to increasing power dissipation when continuous heavy loads or short circuit occurs. Besides, a built-in charge pump is used to drive the N-channel MOSFET that is free of parasitic body diode to eliminate any reversed current flow across the switch when it is powered off.

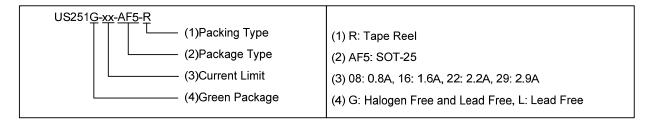
The UTC US251 is applied in high-side power protection switch, USB power management, USB host and self-powered bubs, USB bus-powered hubs, hot plug-in power supplies, battery-charger circuits.

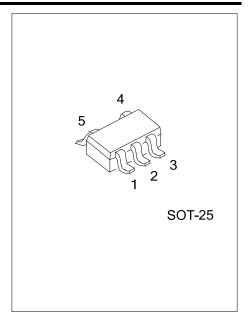
FEATURES

- * Single Power Switch Family
- * 80-mΩ High-Side MOSFET
- * Rated currents of 0.5 A, 1 A, 1.5 A, 2 A
- * Accurate, Fixed, Constant Current Limit
- * Deglitched Fault Reporting
- * Output Discharge When Disabled
- * Reverse Current Blocking
- * Built-in Softstart

ORDERING INFORMATION

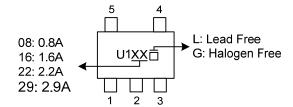
Ordering	Number	Dookogo	Docking	
Lead Free	Halogen Free	Package	Packing	
US251L-xx-AF5-R	US251G-xx-AF5-R	SOT-25	Tape Reel	



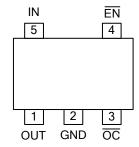


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■ MARKING



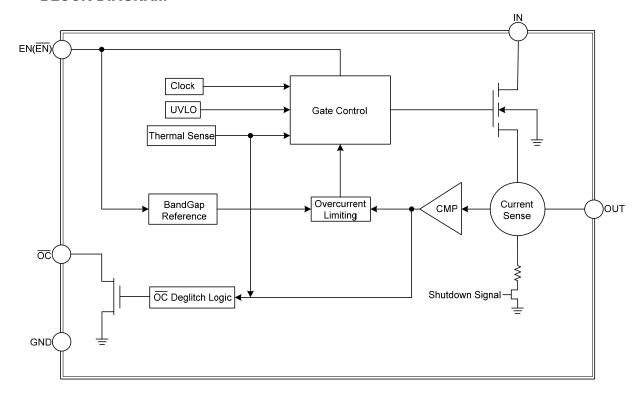
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	OUT	Output MOSFET Source of switch.
2	GND	Ground
3	<u>oc</u>	Open-Drain OC output.
4	EN or EN	Enable input. Make sure EN pin never floating.
5	IN	Power Input Voltage

■ BLOCK DIAGRAM



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■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT	
Supply Voltage	V_{IN}	-0.3 ~ 6	V	
Enable Input Voltage	V_{EN}	-0.3 ~ 6	V	
Flag Voltage	V_{EN}	-0.3 ~ 6	V	
Output Voltage	V _{OUT}	-0.3 ~ 6	V	
Output Current	I _{OUT}	Internally Limited	Α	
Junction Temperature	TJ	+150	°C	
Storage Temperature	T _{STG}	-65 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	250	°C/W

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage, IN	V _{IN}		3.5		5.5	V
Input Voltage, EN or EN	V_{EN}		0		5.5	V
Operating Junction Temperature	T_J		-40		+125	°C
Sink Current Into FLT	I _{FLT}		0		5	mA

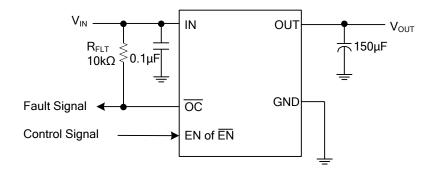
■ ELECTRICAL CHARACTERISTICS

(V_{IN} =5V, C_{IN} = C_{OUT} =1 μ F, T_A =25 $^{\circ}$ C, unless otherwise specified)

$(V_{IN}=5V, C_{IN}=C_{OUT}=1\mu F,$	1A-23 C,				1	1		
PARAMETER		SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
ENABLE INPUT	1						1	
CTL Threshold	Low	V_{IL}	V _{IN} =3.5V~5.5V, Switch OFF				0.8	V
	High	V _{IH}	V _{IN} =3.5V~5.5V, Switch ON		2.0			V
CTL Input Current		I _{I(CTL)}	V _{CTL} =0V~5.5V			0.01		μΑ
UNDER VOLTAGE LOCK	(1	
Under-Voltage Lockout		V_{UVLO}	V _{IN} increasing			2.8		V
Under-Voltage Hysteresis		ΔV_{UVLO}	V _{IN} decreasing			0.1		V
SUPPLY CURRENT			<u> </u>				1	
Supply Current		I _{SW(ON)}	Switch on, V _{OUT} =OPEN			55	70	μΑ
Зирріу Сипепі		I _{SW(OFF)}	Switch off, V _{OUT} =OPEN			0.1	1	μΑ
Output Leakage Current		I _{O(LEAK)}	V_{CTL} =0 V , R_{LOAD} =0 Ω			0.5	10	μΑ
			V _{OUT} =5V, V _{IN} =0V, measure			0.1	1	μΑ
Reverse Leakage Current		I_{REV}		$-40^{\circ}\text{C} \le (T_J, T_A) \le 85^{\circ}\text{C}, V_{OUT} = 5\text{V}, V_{IN} = 0\text{V},$			5	μA
			measure I _{VOUT}					۳,,
CURRENT LIMIT							1 .	
				US251-08	0.6	8.0	1.1	Α
Current Limit		I _{LIMIT}		US251-16	1.2	1.6	1.9	Α
Surroit Limit		·LIMIT		US251-22	1.6	2.2	2.7	Α
				US251-29	2.3	2.9	3.6	Α
Short Circuit Fold-Back Current			V _{OUT} =0V, measured prior to thermal shutdown	US251-08		1		Α
		I _{SC(FB)}		US251-16		1		Α
	Short Should Fold Buok Guitefit			US251-22		1		Α
				US251-29		1		Α
POWER SWITCH			1	I	1			
			I _{OUT} =0.5A	US251-08		80	110	mΩ
Switch ON Resistance		R _{DS(ON)}	I _{OUT} =1.0A	US251-16		80	110	mΩ
			I _{OUT} =1.5A	US251-22		80	110	mΩ
			I _{OUT} =2.0A US251-29			80	110	mΩ
Output Turn-ON Rise Time	e	t _{ON(RISE)}	10% ~ 90% of V _{OUT} rising			400		μs
OVER CURRENT FLAG		.—	\/— 5\/		1	1		
FLAG OFF Current		FLG(OFF)	V _{FLG} =5V			0.01	1	μA
FLAG Output Resistance		RFLG	I _{SINK} =1mA			20	400	Ω
FLAG Delay Time		t_{D}	From fault condition to FLG assertion			10		ms
THERMAL SHUTDOWN			•					
Thermal Shutdown Protection		T_{SD}				130		°C
Thermal Shutdown Hysteresis		ΔT_{SD}				20		°C
Output Discharge								
Output Pull-Down Resista	nce	R_{PD}	V _{IN} =V _{OUT} =5.0V, disabled			400	800	Ω

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■ TYPICAL APPLICATION CIRCUIT



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